TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

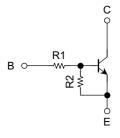
#### RN1701JE, RN1702JE, RN1703JE RN1704JE, RN1705JE, RN1706JE

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications.

Unit in mm

- Two devices are incorporated into an Extreme-Super-Mini (5 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count.
   Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.
- Wide range of resistor values are available to use in various circuit designs.
- Complementary to RN2701JE $\sim$ 2706JE

#### **Equivalent Circuit and Bias Resistor Values**



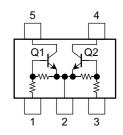
Type No.	R1 (kΩ)	R2 (kΩ)
RN1701JE	4.7	4.7
RN1702JE	10	10
RN1703JE	22	22
RN1704JE	47	47
RN1705JE	2.2	47
RN1706JE	4.7	47

1. BASE 1 (B1)
2. EMITTER (E) 3. BASE 2 (B2) 4. COLLECTOR 2 (C2)
ESV 5. COLLECTOR 1 (C1)
JEDEC —
EIAJ —
TOSHIBA —

### Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	50	V	
Collector-emitter voltage	RN1701JE~1706JE	V <sub>CEO</sub>	50	V	
Emitter-base voltage	RN1701JE~1704JE	\/	10	V	
	RN1705JE, RN1706JE	V <sub>EBO</sub>	5		
Collector current		Ic	100	mA	
Collector power dissipation	RN1701JE~1706JE	P <sub>C</sub> (Note)	100	mW	
Junction temperature	KN17013E~17003E	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

# Equivalent Circuit (top view)



Note: Total rating

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can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the
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## Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1701JE~1706JE	I <sub>CBO</sub>	$V_{CB} = 50 \text{ V}, I_{E} = 0$	_	_	100	nΛ
		I <sub>CEO</sub>	$V_{CE} = 50 \text{ V}, I_B = 0$	_	_	500	nA
Emitter cut-off current	RN1701JE	l <sub>EBO</sub>	V <sub>EB</sub> = 10 V, I <sub>C</sub> = 0	0.82	_	1.52	mA
	RN1702JE			0.38	_	0.71	
	RN1703JE			0.17	_	0.33	
	RN1704JE			0.082	_	0.15	
	RN1705JE			0.078	_	0.145	
	RN1706JE		$V_{EB} = 5 \text{ V}, I_{C} = 0$	0.074	_	0.138	
	RN1701JE			30	_	_	
	RN1702JE			50	_	_	
<b>D</b> O	RN1703JE	1 .	.,	70	_	_	
DC current gain	RN1704JE	- h <sub>FE</sub>	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$	80	_	_	
	RN1705JE	-		80	_	_	
	RN1706JE			80	_	_	
Collector-emitter saturation voltage	RN1701JE~1706JE	V <sub>CE</sub> (sat)	I <sub>C</sub> = 5 mA, I <sub>B</sub> = 0.25 mA	_	0.1	0.3	V
Input voltage (ON)	RN1701JE		V <sub>CE</sub> = 0.2 V, I <sub>C</sub> = 5 mA	1.1	_	2.0	V
	RN1702JE	V <sub>I</sub> (ON)		1.2	_	2.4	
	RN1703JE			1.3	_	3.0	
	RN1704JE			1.5	_	5.0	
	RN1705JE			0.6	_	1.1	
	RN1706JE			0.7	_	1.3	
Input voltage (OFF)	RN1701JE~1704JE	V <sub>I (OFF)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.1 mA	1.0	_	1.5	V
	RN1705JE, 1706JE			0.5	_	0.8	
Transition frequency	RN1701JE~1706JE	f <sub>T</sub>	$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$	_	250	_	MHz
Collector output capacitance	RN1701JE~1706JE	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	3	6	pF
Input resistor	RN1701JE	R1	_	3.29	4.7	6.11	kΩ
	RN1702JE			7	10	13	
	RN1703JE			15.4	22	28.6	
	RN1704JE			32.9	47	61.1	
	RN1705JE			1.54	2.2	2.86	
	RN1706JE			3.29	4.7	6.11	
Resistor ratio	RN1701JE~1704JE	R1/R2	_	0.9	1.0	1.1	
	RN1705JE			0.0421	0.0468	0.0515	
	RN1706JE	1		0.09	0.1	0.11	

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The information contained herein is subject to change without notice.

Type Name	Marking
RN1701JE	Type name  XA
RN1702JE	Type name XB
RN1703JE	Type name X C
RN1704JE	Type name X D
RN1705JE	Type name  XE
RN1706JE	Type name XF